### 1. General description

The 74LVC1G02 provides the single 2-input NOR function.

Input can be driven from either 3.3 V or 5 V devices. These features allow the use of these devices in a mixed 3.3 V and 5 V environment.

Schmitt-trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- $\pm 24$  mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



## 3. Ordering information

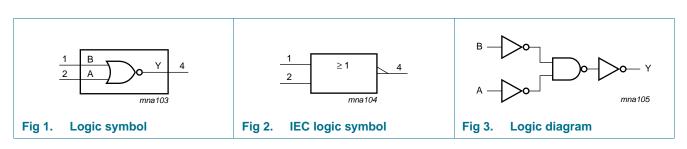
| Table 1. Ordering | g information     |        |  |          |  |  |  |
|-------------------|-------------------|--------|--|----------|--|--|--|
| Type number       | Package           |        |  |          |  |  |  |
|                   | Temperature range | Name   | Description  | Version  |  |  |  |
| 74LVC1G02GW       | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads;<br>body width 1.25 mm  | SOT353-1 |  |  |  |
| 74LVC1G02GV       | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads   | SOT753   |  |  |  |
| 74LVC1G02GM       | –40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm                          | SOT886   |  |  |  |
| 74LVC1G02GF       | –40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm                             | SOT891   |  |  |  |
| 74LVC1G02GN       | –40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm                                  | SOT1115  |  |  |  |
| 74LVC1G02GS       | –40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm                                  | SOT1202  |  |  |  |
| 74LVC1G02GX       | –40 °C to +125 °C | X2SON5 | X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm | SOT1226  |  |  |  |

### 4. Marking

| Table 2. Marking |                             |
|------------------|-----------------------------|
| Type number      | Marking code <sup>[1]</sup> |
| 74LVC1G02GW      | VB                          |
| 74LVC1G02GV      | V02                         |
| 74LVC1G02GM      | VB                          |
| 74LVC1G02GF      | VB                          |
| 74LVC1G02GN      | VB                          |
| 74LVC1G02GS      | VB                          |
| 74LVC1G02GX      | VB                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

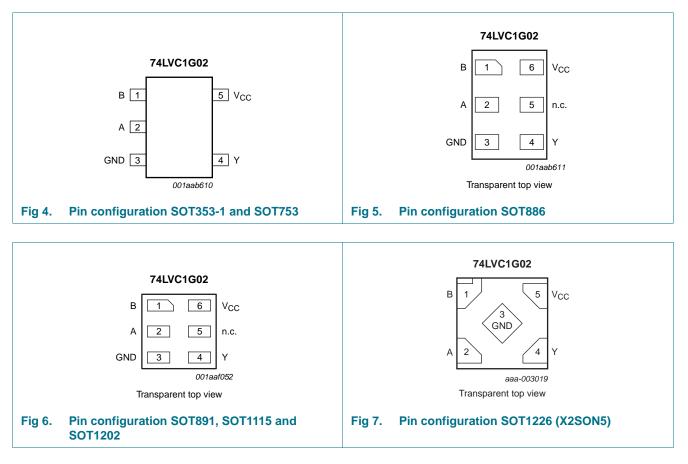
## 5. Functional diagram



74LVC1G02 Product data sheet

#### **Pinning information** 6.

### 6.1 Pinning



### 6.2 Pin description

| SymbolPinDescriptionTSSOP5 and X2SON5XSON6B11A22GND33Y44A2A4                           | Table 3.        | Pin description   |       |                |
|--|-----------------|-------------------|-------|----------------|
| B11data inputA22data inputGND33ground (0 V)Y44data output                              | Symbol          | Pin               |       | Description    |
| A22data inputGND33ground (0 V)Y44data output   |                 | TSSOP5 and X2SON5 | XSON6 |                |
| GND         3         ground (0 V)           Y         4         4         data output | В               | 1                 | 1     | data input     |
| Y     4     4     data output  | А               | 2                 | 2     | data input     |
|  | GND             | 3                 | 3     | ground (0 V)   |
| -  | Y               | 4                 | 4     | data output    |
| n.c 5 not connected  | n.c.            | -                 | 5     | not connected  |
| V <sub>CC</sub> 5 6 supply voltage   | V <sub>CC</sub> | 5                 | 6     | supply voltage |

74LVC1G02 **Product data sheet** 

### 7. Functional description

| Table 4. | Function table <sup>[1]</sup> |   |         |
|----------|-------------------------------|---|---------|
| Inputs   |                               |   | Outputs |
| Α        |                               | В | Y       |
| L        |                               | L | н       |
| L        |                               | Н | L       |
| Н        |                               | L | L       |
| Н        |                               | Н | L       |
|          |                               |   |         |

[1] H = HIGH voltage level; L = LOW voltage level.

### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                                      | Min                | Max                   | Unit |
|------------------|-------------------------|---|--------------------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5               | +6.5                  | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                            | -50                | -                     | mA   |
| VI               | input voltage           |   | <u>[1]</u> –0.5    | +6.5                  | V    |
| Ι <sub>ΟΚ</sub>  | output clamping current | $V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V | -                  | ±50                   | mA   |
| Vo               | output voltage          | Active mode                                     | <u>[1][2]</u> –0.5 | V <sub>CC</sub> + 0.5 | V    |
|                  |                         | Power-down mode                                 | <u>[1][2]</u> –0.5 | +6.5                  | V    |
| I <sub>O</sub>   | output current          | $V_{O} = 0 V$ to $V_{CC}$                       | -                  | ±50                   | mA   |
| I <sub>CC</sub>  | supply current          |   | -                  | +100                  | mA   |
| I <sub>GND</sub> | ground current          |   | -100               | -                     | mA   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$  | <u>[3]</u> _       | 250                   | mW   |
| T <sub>stg</sub> | storage temperature     |   | -65                | +150                  | °C   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When  $V_{CC} = 0 V$  (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

| Table 6.            | Recommended operating condi         | tions                                      |      |     |                 |      |
|---------------------|-------------------------------------|--|------|-----|-----------------|------|
| Symbol              | Parameter                           | Conditions                                 | Min  | Тур | Max             | Unit |
| V <sub>CC</sub>     | supply voltage                      |  | 1.65 | -   | 5.5             | V    |
| VI                  | input voltage                       |  | 0    | -   | 5.5             | V    |
| Vo                  | output voltage                      | Active mode                                | 0    | -   | V <sub>CC</sub> | V    |
|                     |                                     | V <sub>CC</sub> = 0 V; Power-down mode     | 0    | -   | 5.5             | V    |
| T <sub>amb</sub>    | ambient temperature                 |  | -40  | -   | +125            | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC}$ = 1.65 V to 2.7 V                 | -    | -   | 20              | ns/V |
|                     |                                     | $V_{CC} = 2.7 \text{ V to } 5.5 \text{ V}$ | -    | -   | 10              | ns/V |
|                     |                                     |  |      |     |                 |      |

### **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter             | Conditions   | -40 °        | °C to +8             | 5 °C         | -40 °C to           | Unit               |    |
|-----------------|-----------------------|--|--------------|----------------------|--------------|---------------------|--------------------|----|
|                 |                       |  | Min          | Typ <mark>[1]</mark> | Max          | Min                 | Max                |    |
| VIH             | HIGH-level            | $V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$               | $0.65V_{CC}$ | -                    | -            | 0.65V <sub>CC</sub> | -                  | V  |
|                 | input voltage         | $V_{CC}$ = 2.3 V to 2.7 V  | 1.7          | -                    | -            | 1.7                 | -                  | V  |
|                 |                       | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$                         | 2.0          | -                    | -            | 2.0                 | -                  | V  |
|                 |                       | $V_{CC}$ = 4.5 V to 5.5 V  | $0.7V_{CC}$  | -                    | -            | $0.7V_{CC}$         | -                  | V  |
| VIL             | LOW-level             | $V_{CC}$ = 1.65 V to 1.95 V  | -            | -                    | $0.35V_{CC}$ | -                   | $0.35V_{CC}$       | V  |
|                 | input voltage         | $V_{CC}$ = 2.3 V to 2.7 V  | -            | -                    | 0.7          | -                   | 0.7                | V  |
|                 |                       | $V_{CC}$ = 2.7 V to 3.6 V  | -            | -                    | 0.8          | -                   | 0.8                | V  |
|                 |                       | $V_{CC}$ = 4.5 V to 5.5 V  | -            | -                    | $0.3V_{CC}$  | -                   | 0.3V <sub>CC</sub> | V  |
| V <sub>OH</sub> | HIGH-level            | $V_{I} = V_{IH} \text{ or } V_{IL}$                                |              |                      |              |                     |                    |    |
|                 | output voltage        | $I_{O} = -100 \ \mu A;$<br>$V_{CC} = 1.65 \ V \text{ to } 5.5 \ V$ | $V_{CC}-0.1$ | -                    | -            | $V_{CC}-0.1$        | -                  | V  |
|                 |                       | $I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$                   | 1.2          | -                    | -            | 0.95                | -                  | V  |
|                 |                       | $I_0 = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$                      | 1.9          | -                    | -            | 1.7                 | -                  | V  |
|                 |                       | $I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$                   | 2.2          | -                    | -            | 1.9                 | -                  | V  |
|                 |                       | $I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$                   | 2.3          | -                    | -            | 2.0                 | -                  | V  |
|                 |                       | $I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$                   | 3.8          | -                    | -            | 3.4                 | -                  | V  |
| V <sub>OL</sub> | LOW-level             | $V_{I} = V_{IH} \text{ or } V_{IL}$                                |              |                      |              |                     |                    |    |
|                 | output voltage        | I <sub>O</sub> = 100 μA;<br>V <sub>CC</sub> = 1.65 V to 5.5 V      | -            | -                    | 0.1          | -                   | 0.1                | V  |
|                 |                       | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                    | -            | -                    | 0.45         | -                   | 0.70               | V  |
|                 |                       | $I_0 = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$                       | -            | -                    | 0.3          | -                   | 0.45               | V  |
|                 |                       | $I_{O}$ = 12 mA; $V_{CC}$ = 2.7 V                                  | -            | -                    | 0.4          | -                   | 0.60               | V  |
|                 |                       | $I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$                    | -            | -                    | 0.55         | -                   | 0.80               | V  |
|                 |                       | $I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$                    | -            | -                    | 0.55         | -                   | 0.80               | V  |
| I               | input leakage current | $V_I = 5.5 V \text{ or GND};$<br>$V_{CC} = 0 V \text{ to } 5.5 V$  | -            | ±0.1                 | ±5           | -                   | ±100               | μA |

| Symbol           | Parameter                       | Conditions  | -40 | °C to +85            | °C  | –40 °C to +125 °C |      | Unit |
|------------------|---------------------------------|---|-----|----------------------|-----|-------------------|------|------|
|                  |                                 |   | Min | Typ <mark>[1]</mark> | Max | Min               | Max  |      |
| I <sub>OFF</sub> | power-off<br>leakage<br>current | $V_{CC} = 0$ V; $V_{I}$ or $V_{O} = 5.5$ V  | -   | ±0.1                 | ±10 | -                 | ±200 | μA   |
| I <sub>CC</sub>  | supply current                  | $V_{I} = 5.5 V \text{ or GND}; I_{O} = 0 A;$<br>$V_{CC} = 1.65 V \text{ to } 5.5 V$ | -   | 0.1                  | 10  | -                 | 200  | μA   |
| $\Delta I_{CC}$  | additional supply current       |   | -   | 5                    | 500 | -                 | 5000 | μΑ   |
| CI               | input<br>capacitance            | $V_{CC}$ = 3.3 V; $V_{I}$ = GND to $V_{CC}$   | -   | 5                    | -   | -                 | -    | pF   |

#### Table 7. Static characteristics ... continued

~ • •

[1] All typical values are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

### **11. Dynamic characteristics**

#### **Dynamic characteristics** Table 8.

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 9.

| Symbol          | Parameter                     | Conditions  |            | –40 °C to +85 °C |                      |     | –40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------|---|------------|------------------|----------------------|-----|-------------------|------|------|
|                 |                               |   |            | Min              | Typ <mark>[1]</mark> | Max | Min               | Мах  |      |
| t <sub>pd</sub> | propagation delay             | A, B to Y; see Figure 8                                     | [2]        |                  |                      |     |                   |      |      |
|                 |                               | $V_{CC}$ = 1.65 V to 1.95 V                                 |            | 1.0              | 3.2                  | 8.0 | 1.0               | 10.5 | ns   |
|                 |                               | $V_{CC}$ = 2.3 V to 2.7 V                                   |            | 0.5              | 2.2                  | 5.5 | 0.5               | 7.0  | ns   |
|                 |                               | $V_{CC} = 2.7 V$  |            | 0.5              | 2.5                  | 5.5 | 0.5               | 7.0  | ns   |
|                 |                               | $V_{CC}$ = 3.0 V to 3.6 V                                   |            | 0.5              | 2.1                  | 4.5 | 0.5               | 6.0  | ns   |
|                 |                               | $V_{CC}$ = 4.5 V to 5.5 V                                   |            | 0.5              | 1.7                  | 4.0 | 0.5               | 5.5  | ns   |
| $C_{PD}$        | power dissipation capacitance | $V_1 = GND \text{ to } V_{CC};$<br>$V_{CC} = 3.3 \text{ V}$ | <u>[3]</u> | -                | 14                   | -   | -                 | -    | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D$  =  $C_{PD} \times V_{CC}{}^2 \times f_i \times N$  +  $\Sigma (C_L \times V_{CC}{}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

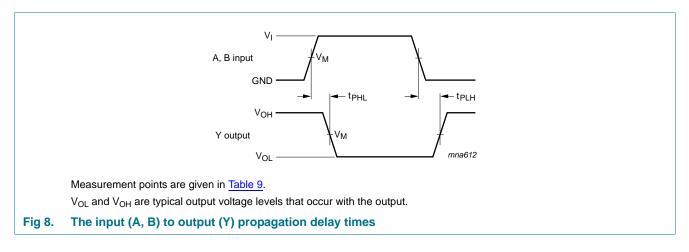
 $C_{L}$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

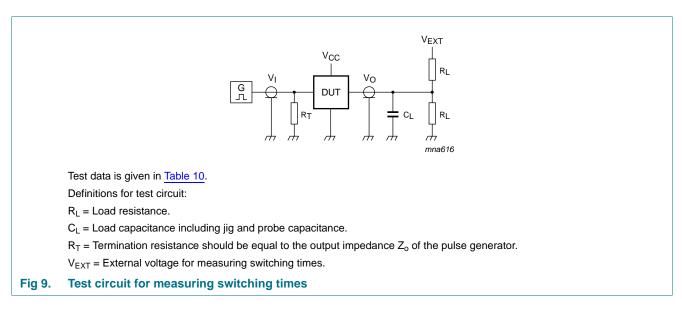
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 12. Waveforms



#### Table 9. Measurement points

| Supply voltage   | Input              | Output             |
|------------------|--------------------|--------------------|
| V <sub>cc</sub>  | V <sub>M</sub>     | V <sub>M</sub>     |
| 1.65 V to 1.95 V | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> |
| 2.3 V to 2.7 V   | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> |
| 2.7 V            | 1.5 V              | 1.5 V              |
| 3.0 V to 3.6 V   | 1.5 V              | 1.5 V              |
| 4.5 V to 5.5 V   | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> |



### **NXP Semiconductors**

## 74LVC1G02

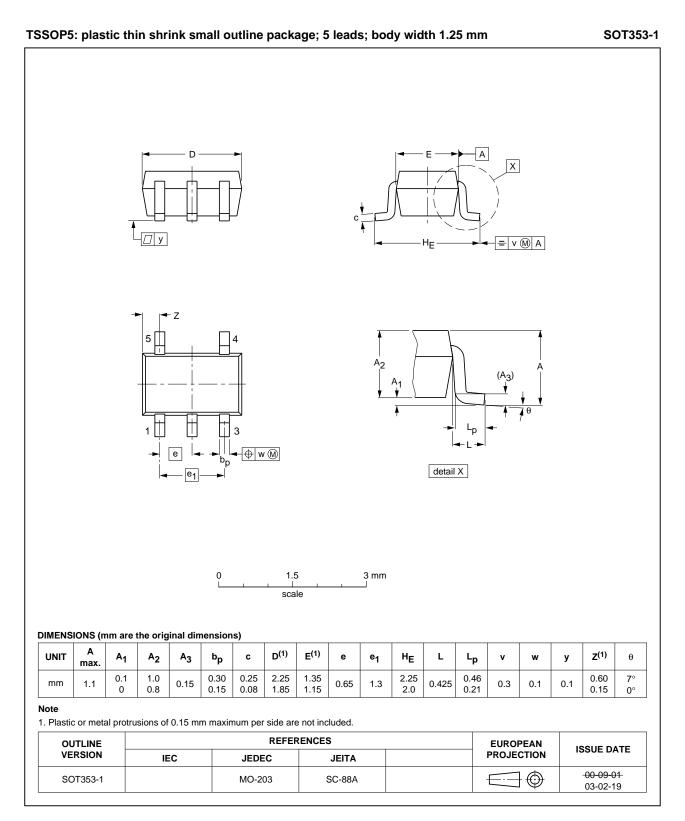
Single 2-input NOR gate

| Supply voltage   | Input           |               | Load  |       | V <sub>EXT</sub>                    |
|------------------|-----------------|---------------|-------|-------|-------------------------------------|
| V <sub>cc</sub>  | VI              | $t_r = t_f$   | CL    | RL    | t <sub>PLH</sub> , t <sub>PHL</sub> |
| 1.65 V to 1.95 V | V <sub>CC</sub> | $\leq$ 2.0 ns | 30 pF | 1 kΩ  | open                                |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | $\leq$ 2.0 ns | 30 pF | 500 Ω | open                                |
| 2.7 V            | 2.7 V           | $\leq$ 2.5 ns | 50 pF | 500 Ω | open                                |
| 3.0 V to 3.6 V   | 2.7 V           | $\leq$ 2.5 ns | 50 pF | 500 Ω | open                                |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns      | 50 pF | 500 Ω | open                                |

74LVC1G02

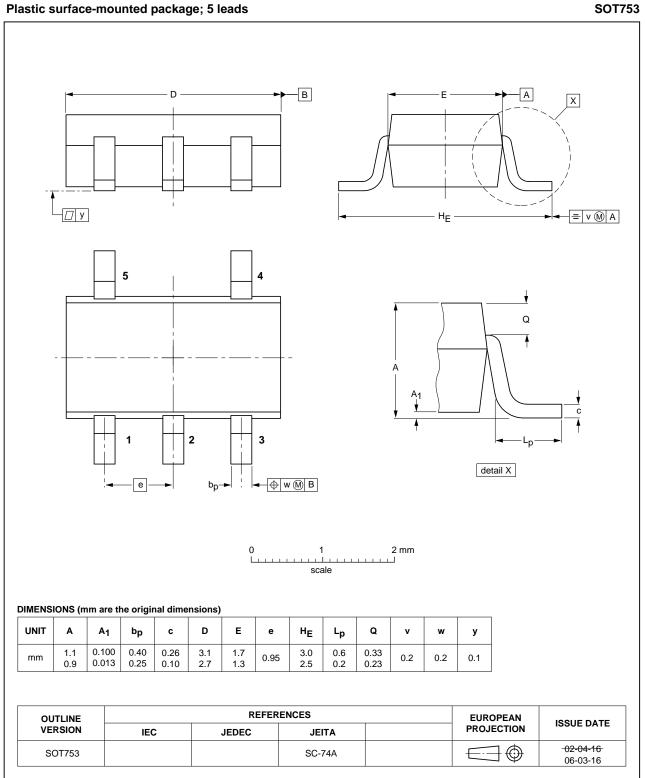
Single 2-input NOR gate

### 13. Package outline



#### Fig 10. Package outline SOT353-1 (TSSOP5)

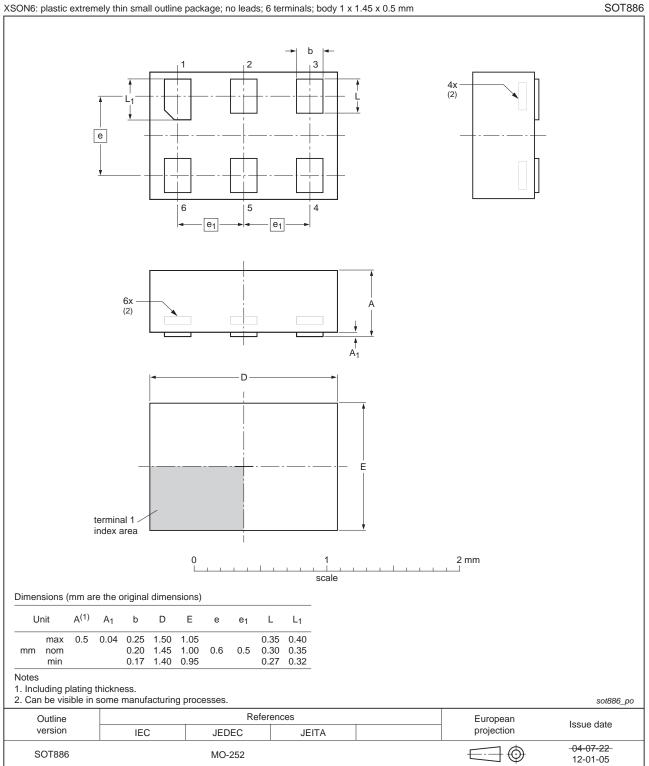
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#### Plastic surface-mounted package; 5 leads

Fig 11. Package outline SOT753 (SC-74A)

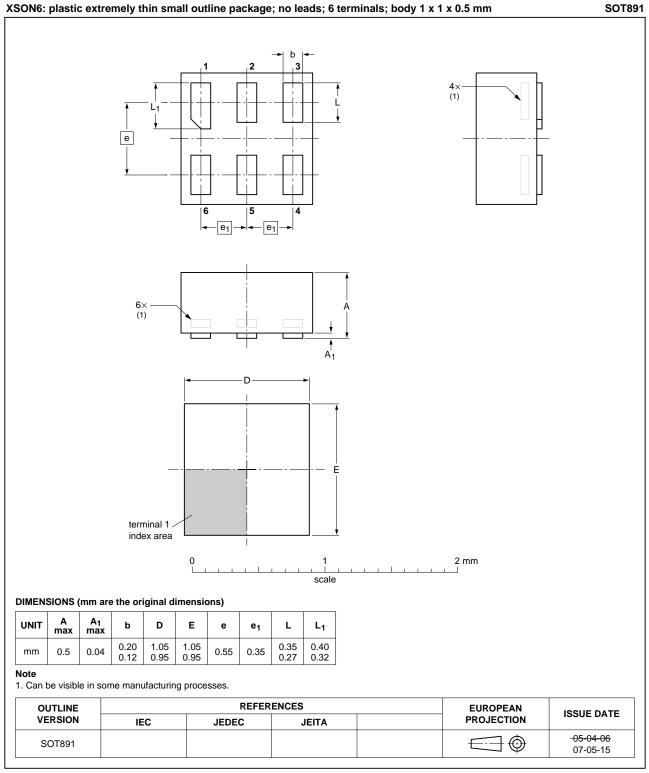
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# XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

Fig 12. Package outline SOT886 (XSON6)

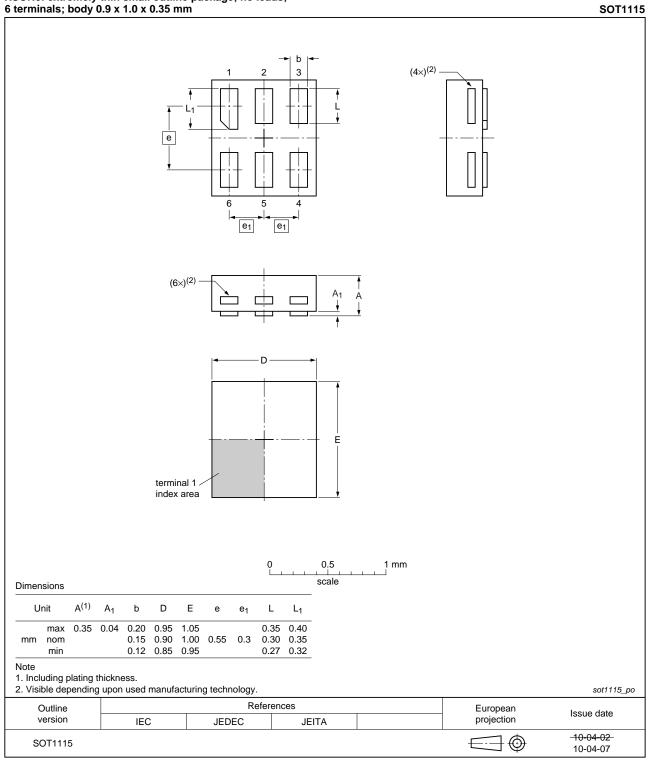
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### XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

Fig 13. Package outline SOT891 (XSON6)

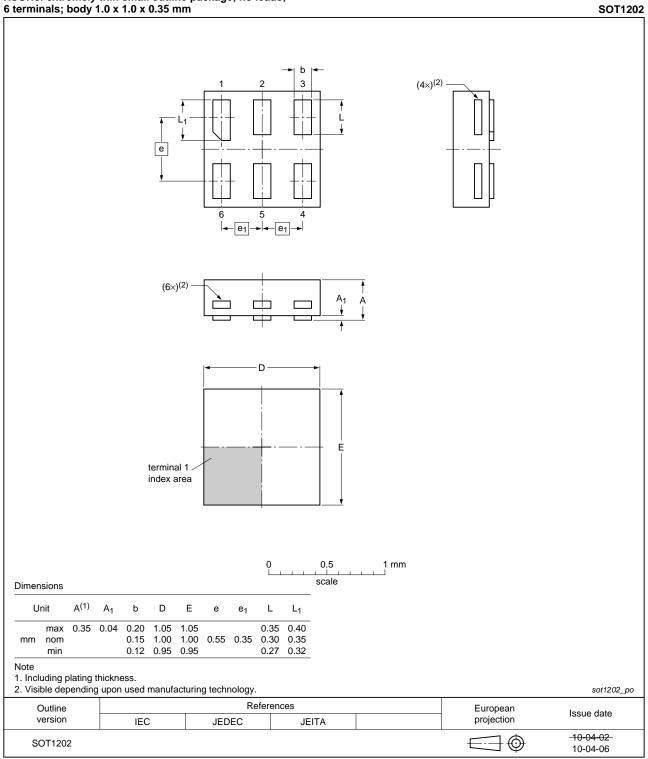
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# XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 14. Package outline SOT1115 (XSON6)

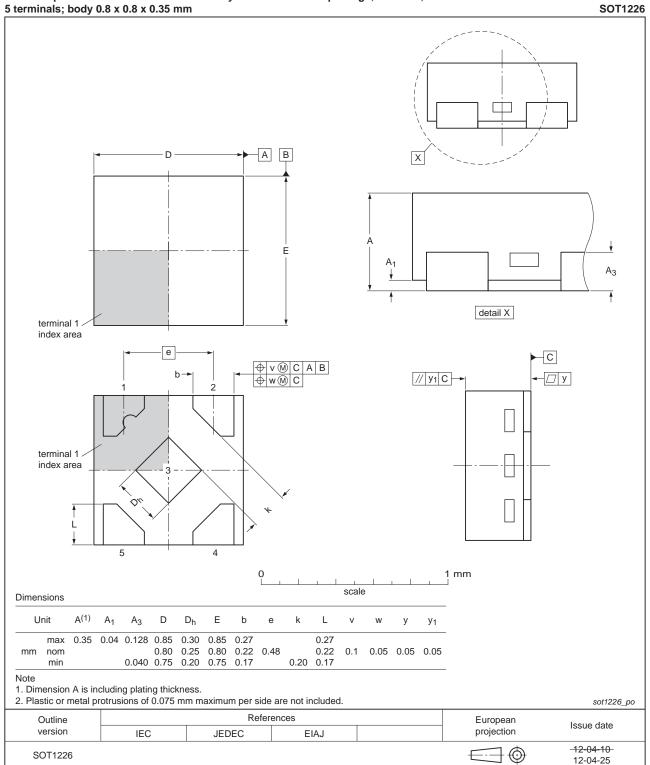
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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)

74LVC1G02 **Product data sheet** 



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm

#### Fig 16. Package outline SOT1226 (X2SON5)

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### 14. Abbreviations

| Table 11. Abbreviations |   |  |  |  |
|-------------------------|---|--|--|--|
| Acronym                 | Description                             |  |  |  |
| CMOS                    | Complementary Metal Oxide Semiconductor |  |  |  |
| DUT                     | Device Under Test                       |  |  |  |
| ESD                     | ElectroStatic Discharge                 |  |  |  |
| HBM                     | Human Body Model                        |  |  |  |
| MM                      | Machine Model                           |  |  |  |
| TTL                     | Transistor-Transistor Logic             |  |  |  |
|                         |   |  |  |  |

## 15. Revision history

| Table 12. Revision | history                         |                             |                     |                |
|--------------------|---------------------------------|-----------------------------|---------------------|----------------|
| Document ID        | Release date                    | Data sheet status           | Change notice       | Supersedes     |
| 74LVC1G02 v.11     | 20120629                        | Product data sheet          | -                   | 74LVC1G02 v.10 |
| Modifications:     | <ul> <li>Added type</li> </ul>  | number 74LVC1G02GX (S       | OT1226)             |                |
| 74LVC1G02 v.10     | 20120305                        | Product data sheet          | -                   | 74LVC1G02 v.9  |
| Modifications:     | <ul> <li>Package ou</li> </ul>  | Itline drawing of SOT886 (F | igure 12) modified. |                |
| 74LVC1G02 v.9      | 20111209                        | Product data sheet          | -                   | 74LVC1G02 v.8  |
| Modifications:     | <ul> <li>Legal pages</li> </ul> | s updated.                  |                     |                |
| 74LVC1G02 v.8      | 20101020                        | Product data sheet          | -                   | 74LVC1G02 v.7  |
| 74LVC1G02 v.7      | 20070718                        | Product data sheet          | -                   | 74LVC1G02 v.6  |
| 74LVC1G02 v.6      | 20060914                        | Product data sheet          | -                   | 74LVC1G02 v.5  |
| 74LVC1G02 v.5      | 20040907                        | Product specification       | -                   | 74LVC1G02 v.4  |
| 74LVC1G02 v.4      | 20021002                        | Product specification       | -                   | 74LVC1G02 v.3  |
| 74LVC1G02 v.3      | 20020515                        | Product specification       | -                   | 74LVC1G02 v.2  |
| 74LVC1G02 v.2      | 20010411                        | Product specification       | -                   | 74LVC1G02 v.1  |
| 74LVC1G02 v.1      | 20001114                        | Product specification       | -                   | -              |
|                    |                                 |                             |                     |                |

### 16. Legal information

### 16.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 16.2 Definitions

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## 74LVC1G02

### **18. Contents**

| 1    | General description 1              |
|------|------------------------------------|
| 2    | Features and benefits 1            |
| 3    | Ordering information 2             |
| 4    | Marking 2                          |
| 5    | Functional diagram 2               |
| 6    | Pinning information 3              |
| 6.1  | Pinning 3                          |
| 6.2  | Pin description 3                  |
| 7    | Functional description 4           |
| 8    | Limiting values 4                  |
| 9    | Recommended operating conditions 5 |
| 10   | Static characteristics 5           |
| 11   | Dynamic characteristics 6          |
| 12   | Waveforms                          |
| 13   | Package outline 9                  |
| 14   | Abbreviations                      |
| 15   | Revision history 16                |
| 16   | Legal information 17               |
| 16.1 | Data sheet status 17               |
| 16.2 | Definitions 17                     |
| 16.3 | Disclaimers                        |
| 16.4 | Trademarks 18                      |
| 17   | Contact information 18             |
| 18   | Contents 19                        |

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